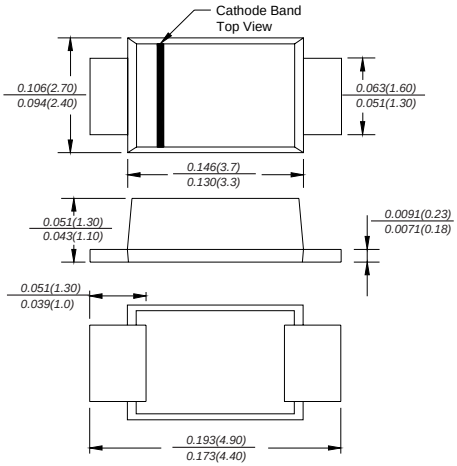
SS12F THRU SS1200F

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

SMAF



Dimensions in inches and (millimeters)

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction,majority carrier conduction
- Low power loss,high efficiency
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260℃/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC SMAF molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight:0.0018 ounce, 0.064 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

MDD Catalog Number	*SYMBOLS*	SS12F	SS13F	SS14F	SS15F	SS16F	SS18F	SS110F	SS1150F	SS1200F	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T_L(see fig.1)	$I_{(AV)}$	1.0									Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30.0									Amps
Maximum instantaneous forward voltage at 1.0A	V_F	0.55				0.70		0.85		0.95	Volts
Maximum DC reverse current T_A=25℃	I_R	0.5								0.2	mA
at rated DC blocking voltage T_A=100℃		10.0						5.0		2.0	
Typical junction capacitance (NOTE 1)	C_J	110				90					pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	88.0									°C/W
Operating junction temperature range	T_J,	-50 to +125						-50 to +150			°C
Storage temperature range	T_{STG}	-50 to +150									°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

www.microdiode.com

RATINGS AND CHARACTERISTIC CURVES SS12F THRU SS1200F

FIG. 1- FORWARD CURRENT DERATING CURVE

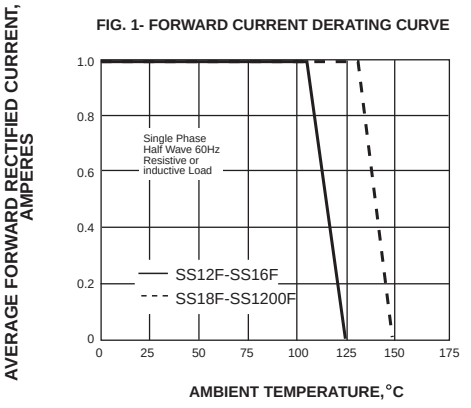


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

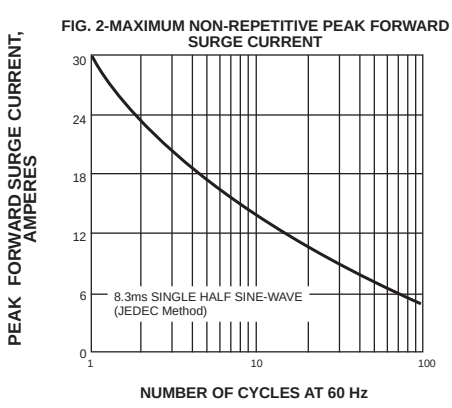


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

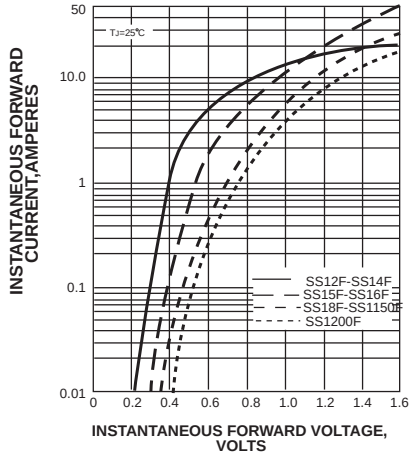


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

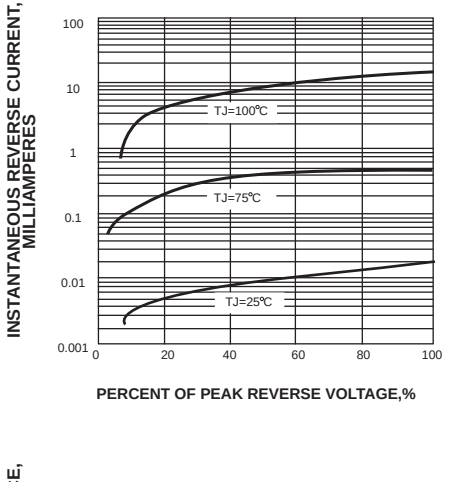


FIG. 5-TYPICAL JUNCTION CAPACITANCE

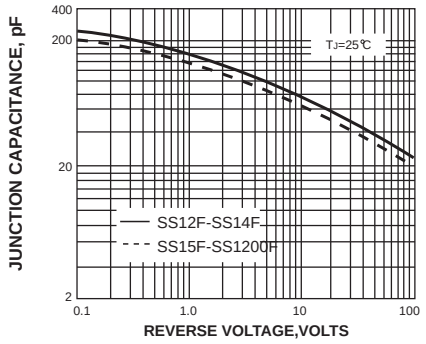
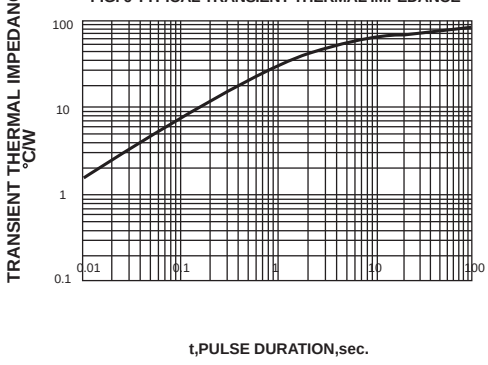


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!

www.microdiode.com